DESCRIPTION

The SPN1306 is the N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

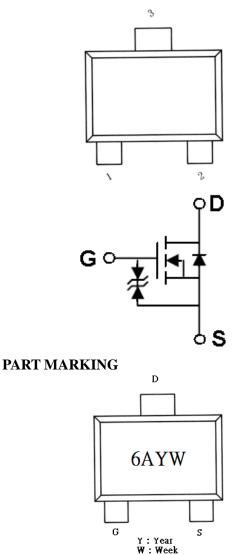
APPLICATIONS

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

- N-Channel 30V/0.95A,RDs(ON)=550mΩ@VGs=4.5V 30V/0.75A,RDs(ON)=650mΩ@VGs=2.5V 30V/0.65A,RDs(ON)=850mΩ@VGs=1.8V
- Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- SOT-323 package design

PIN CONFIGURATION(SOT-323)





PIN DESCRIPTION						
Pin	Symbol	Description				
1	G	Gate				
2	S	Source				
3	D	Drain				

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1306S32RGB	SOT-323	6A

* SPN1306S32RGB : Tape Reel ; Pb – Free ; Halogen – Free ; 3K/Reel

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

Parameter		Symbol	Typical	Unit
Drain-Source Voltage		Vdss	30	V
Gate –Source Voltage		VGSS	±12	V
Continuous Drain Current(TJ=150°C)	TA=25°C	Id	0.65	А
Pulsed Drain Current		Idm	2.8	Α
Continuous Source Current(Diode Conduction)		Is	0.3	А
Power Dissipation	TA=25°C	Pd	0.15	W
Operating Junction Temperature		TJ	-55/150	°C
Storage Temperature Range		Tstg	-55/150	°C

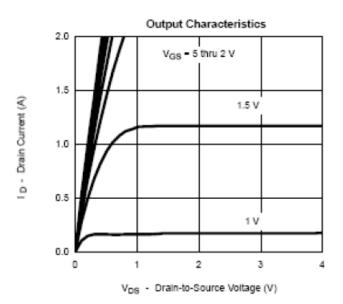


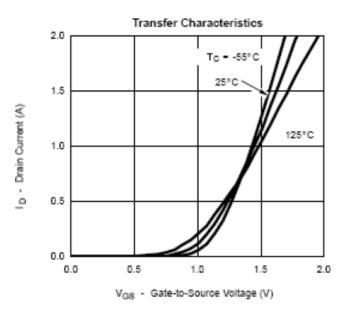
ELECTRICAL CHARACTERISTICS

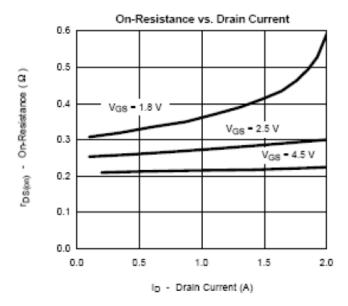
(TA=25°C Unless otherwise noted)

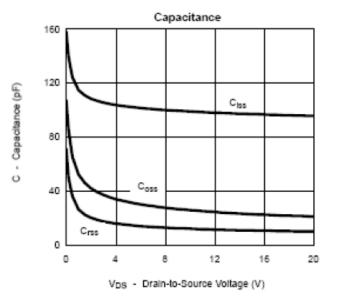
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit
Static		·				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID= 250uA	30			V
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.35		1.0	V
Gate Leakage Current	IGSS	VDS=0V,VGS=±12V			30	uA
		VDS= 24V, VGS=0V			1	
Zero Gate Voltage Drain Current	Idss	Vds= 24V,Vgs=0V Tj=55°C			5	uA
On-State Drain Current	ID(on)	$V_{DS} \ge 4.5V, V_{GS} = 5V$	0.7			А
	RDS(on)	Vgs=4.5V,Id=0.95A		0.45	0.55	Ω
Drain-Source On-Resistance		Vgs=2.5V,Id=0.75A		0.50	0.65	
		VGS=1.8V,ID=0.65A		0.75	0.85	
Forward Transconductance	gfs	VDS=10V,ID=0.4A		1.0		S
Diode Forward Voltage	Vsd	Is=0.15A,Vgs=0V		0.8	1.2	V
Dynamic						
Total Gate Charge	Qg	Vds=10V,Vgs=4.5V,		1.2	1.5	nC
Gate-Source Charge	Qgs	ID=0.6A		0.2		
Gate-Drain Charge	Qgd			0.3		
Turn On Times	td(on)	$V_{DD}=10V,RL=10\Omega$,		5	10	ns
Turn-On Time	tr	ID=0.5A		8	15	
	td(off)	VGEN=4.5V, RG=6 Ω		10	18	
Turn-Off Time	tf			1.2	2.8	

TYPICAL CHARACTERISTICS

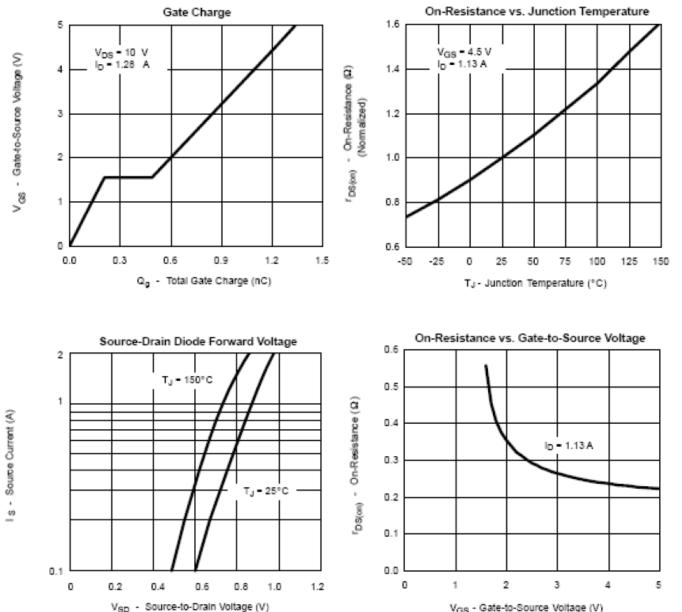






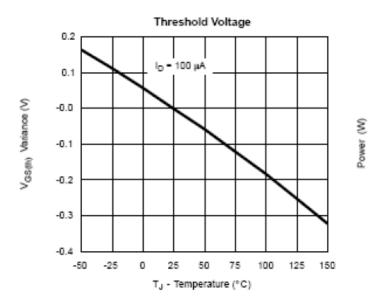


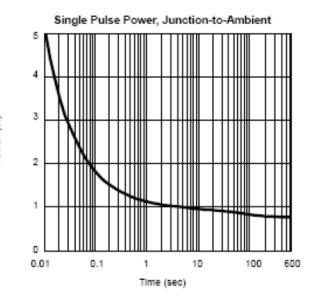
TYPICAL CHARACTERISTICS



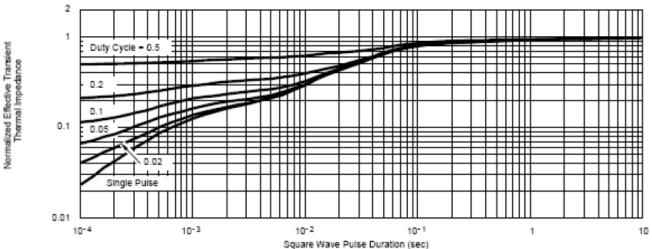
VGS - Gate-to-Source Voltage (V)

TYPICAL CHARACTERISTICS

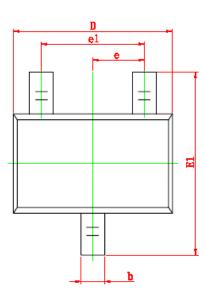


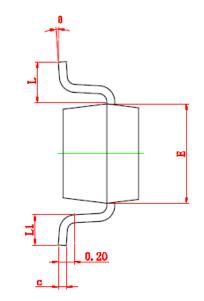


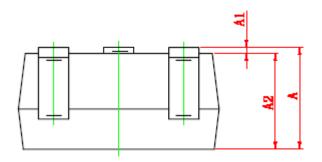
Normalized Thermal Transient Impedance, Junction-to-Foot



SOT-323 PACKAGE OUTLINE







Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650 TYP		0.026	6 TYP	
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	



Information provided is alleged to be exact and consistent. SYNC Power Corporation presumes no responsibility for the penalties of use of such information or for any violation of patents or other rights of third parties which may result from its use. No license is granted by allegation or otherwise under any patent or patent rights of SYNC Power Corporation. Conditions mentioned in this publication are subject to change without notice. This publication surpasses and replaces all information previously supplied. SYNC Power Corporation products are not authorized for use as critical components in life support devices or systems without express written approval of SYNC Power Corporation.

© The SYNC Power logo is a registered trademark of SYNC Power Corporation © 2004 SYNC Power Corporation – Printed in Taiwan – All Rights Reserved SYNC Power Corporation 7F-2, No.3-1, Park Street NanKang District (NKSP), Taipei, Taiwan 115 Phone: 886-2-2655-8178 Fax: 886-2-2655-8468 © http://www.syncpower.com